

FMI11N60E

FUJI POWER MOSFET

Super FAP-E³ series

N-CHANNEL SILICON POWER MOSFET

■ Features

Maintains both low power loss and low noise Lower R_{DS}(on) characteristic More controllable switching dv/dt by gate resistance Smaller V_{GS} ringing waveform during switching Narrow band of the gate threshold voltage (3.0±0.5V) High avalanche durability

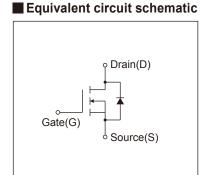
Applications

Switching regulators UPS (Uninterruptible Power Supply) DC-DC converters

Maximum Ratings and Characteristics

● Absolute Maximum Ratings at Tc=25°C (unless otherwise specified)

Outline Drawings [mm]					
T-Pack(L)	-1,390,2 -1,390,2 				
+ + + ① ② ①	CONNECTION (C) GATE (C) DRAIN (D) SOURCE DIMENSIONS ARE IN MILLIMETERS.				



Description	Symbol	Characteristics	Unit	Remarks
Drain Source Voltage	V _{DS}	600	V	
Drain-Source Voltage	V _{DSX}	600	V	V _{GS} = -30V
Continuous Drain Current	ID	±11	Α	
Pulsed Drain Current	I _{DP}	±44	Α	
Gate-Source Voltage	V _{GS}	±30	V	
Repetitive and Non-Repetitive Maximum AvalancheCurrent	Iar	11	Α	Note*1
Non-Repetitive Maximum Avalanche Energy	Eas	384	mJ	Note*2
Repetitive Maximum Avalanche Energy	Ear	18.0	mJ	Note*3
Peak Diode Recovery dV/dt	dV/dt	4.9	kV/μs	Note*4
Peak Diode Recovery -di/dt	-di/dt	100	A/µs	Note*5
Maximum Power Dissipation	Po	1.67	14/	Ta=25°C
		180	W	Tc=25°C
Operating and Storage Temperature range	Tch	150	°C	
	T _{stg}	-55 to + 150	°C	

● Electrical Characteristics at Tc=25°C (unless otherwise specified)

Description	Symbol	Conditions	Conditions		typ.	max.	Unit
Drain-Source Breakdown Voltage	BVDSS	I _D =250µA, V _{GS} =0V		600	-	-	V
Gate Threshold Voltage	V _{GS} (th)	In=250µA, Vos=Vgs	In=250µA, Vns=Vgs		3.0	3.5	V
Zero Gate Voltage Drain Current		V _{DS} =600V, V _{GS} =0V	T _{ch} =25°C	-	-	25	μA
	IDSS	V _{DS} =480V, V _{GS} =0V	Tch=125°C	-	-	250	
Gate-Source Leakage Current	Igss	V _{GS} =±30V, V _{DS} =0V		-	10	100	nA
Drain-Source On-State Resistance	R _{DS} (on)	I _D =5.5A, V _{GS} =10V		-	0.64	0.75	Ω
Forward Transconductance	g _{fs}	I _D =5.5A, V _{DS} =25V		6	12	-	S
Input Capacitance	Ciss	V _{DS} =25V V _{GS} =0V		-	1700	2550	pF
Output Capacitance	Coss			-	150	225	
Reverse Transfer Capacitance	Crss	f=1MHz	ИНz - 1		11	16.5	
Turn-On Time	td(on)	V_{cc} =300V V_{ds} =10V I_{D} =5.5A R_{c} =15 Ω		-	21	31.5	ns
	tr			-	9.5	14.3	
Turn-Off Time	td(off)			-	100	150	
	tf			-	19	28.5	
Total Gate Charge	Q _G	Vcc=300V	V _{cc} =300V		48.5	73	nC
Gate-Source Charge	QGS	I _D =11A V _{SS} =10V		-	12.5	19	
Gate-Drain Charge	Q _{GD}			-	14	21	
Avalanche Capability	lav	L=2.64mH, Tch=25°C	L=2.64mH, T _{ch} =25°C		-	-	А
Diode Forward On-Voltage	V _{SD}	I _F =11A, V _{GS} =0V, T _{ch} =25°0	I _F =11A, V _{GS} =0V, T _{ch} =25°C		0.86	1.30	V
Reverse Recovery Time	trr	I _F =11A, V _{GS} =0V	I _F =11A, V _{GS} =0V		0.52	-	μS
Reverse Recovery Charge	Qrr	-di/dt=100A/µs, Tch=25	-di/dt=100A/µs, Tch=25°C		5.5	-	μC

Thermal Characteristics

Description	Symbol	Test Conditions	min.	typ.	max.	Unit
Thermal resistance	Rth (ch-c)	Channel to Case			0.690	°C/W
	Rth (ch-a)	Channel to Ambient			75.0	°C/W

Note *1 : Tch≤150°C

Note 12: Stating Tch=25°C, Ias=5A, L=28.2mH, Vcc=60V, Re=50Ω

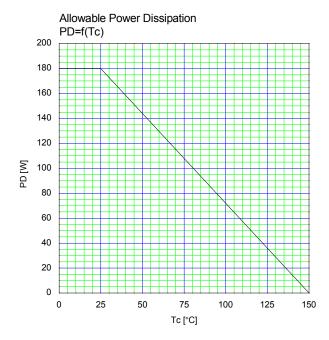
Eas limited by maximum channel temperature and avalanche current.

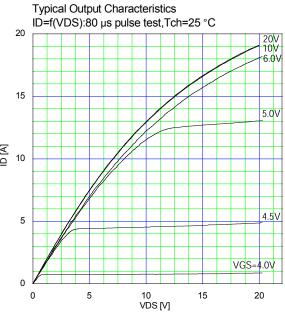
See to 'Avalanche Energy' graph.

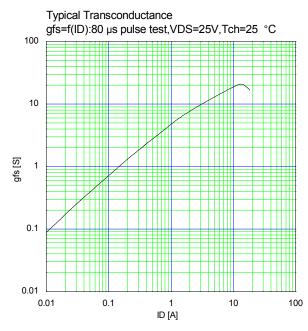
Note $^{\star}3$: Repetitive rating : Pulse width limited by maximum channel temperature.

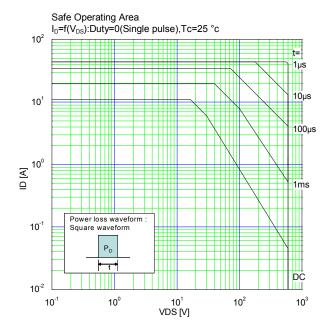
See to the 'Transient Themal impeadance' graph.

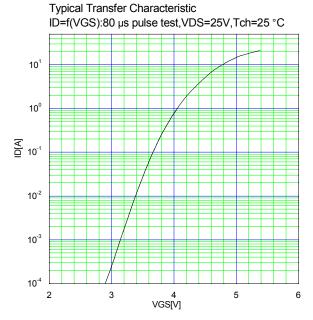
Note *4 : Ir≤-Ip, -di/dt=100A/µs, Vcc≤BVpss, Tch≤150°C.
Note *5 : Ir≤-Ip, dv/dt=4.4kV/µs, Vcc≤BVpss, Tch≤150°C.

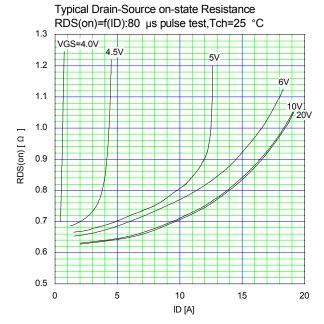


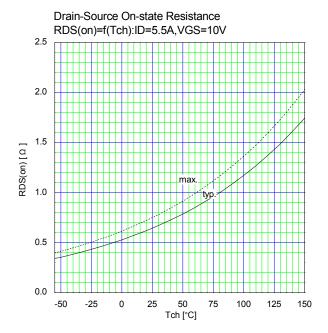


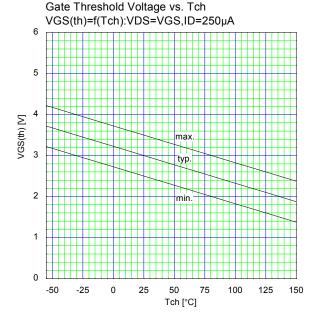


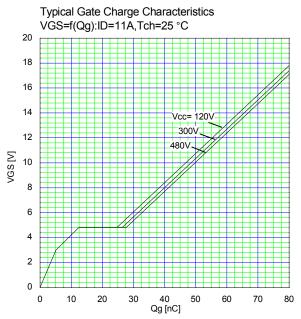


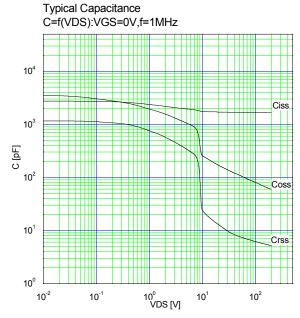


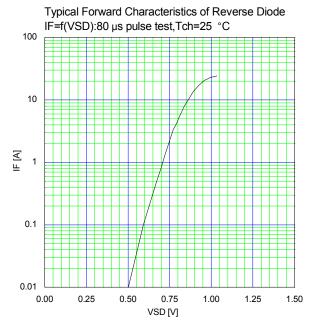


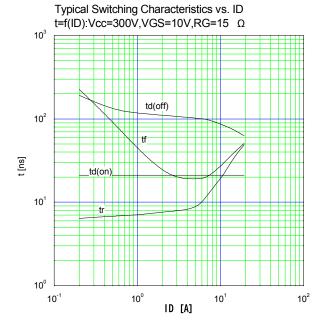




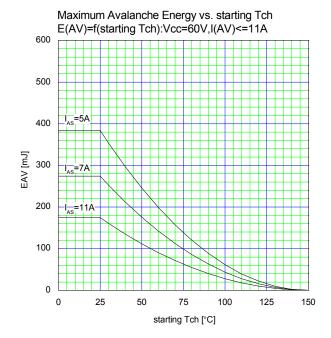


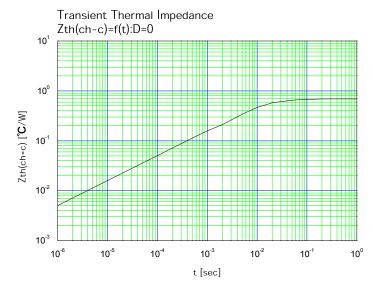






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